



March 1988

MM54C48/MM74C48 BCD-to-7 Segment Decoder

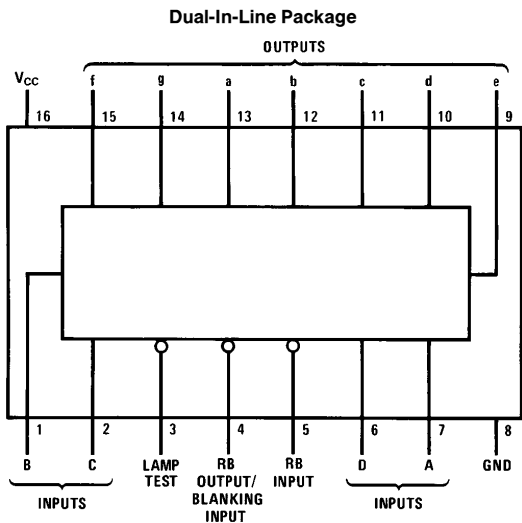
General Description

The MM54C48/MM74C48 BCD-to-7 segment decoder is a monolithic complementary MOS (CMOS) integrated circuit constructed with N- and P-channel enhancement transistors. Seven NAND gates and one driver are connected in pairs to make binary-coded decimal (BCD) data and its complement available to the seven decoding AND-OR-INVERT gates. The remaining NAND gate and three input buffers provide test-blanking input/ripple-blanking output, and ripple-blanking inputs.

Features

- Wide supply voltage range 3.0V to 15V
- Guaranteed noise margin 1.0V
- High noise immunity 0.45 V_{CC} (typ.)
- Low power fan out of 2 driving 74L
- High current sourcing output (up to 50 mA)
- Ripple blanking for leading or trailing zeros (optional)
- Lamp test provision

Connection Diagram

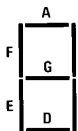


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Top View

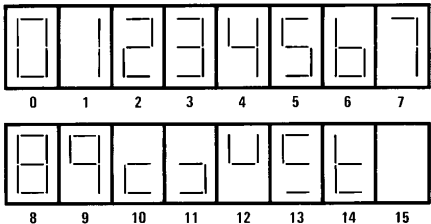
Order Number MM54C48 or MM74C48

Segment Identification



TL/F/5883-2

Numerical Designations and Resultant Displays



TL/F/5883-3

MM54C48/MM74C48 BCD-to-7 Segment Decoder

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Voltage at Any Pin	−0.3V to $V_{CC} + 0.3V$
Operating Temperature Range	−55°C to +125°C MM54C48 −40°C to +85°C MM74C48
Storage Temperature Range	−65°C to +150°C

Power Dissipation	700 mW
Dual-In-Line	
Small Outline	500 mW
Operating V_{CC} Range	3.0V to 15V
Absolute Maximum V_{CC}	18V
Lead Temperature (Soldering, 10 seconds)	260°C

DC Electrical Characteristics Min/Max limits apply across temperature range unless otherwise noted

Symbol	Parameter	Conditions	Min	Typ	Max	Units
CMOS to CMOS						
V _{IN(1)}	Logical “1” Input Voltage	V _{CC} = 5.0V	3.5			V
		V _{CC} = 10V	8.0			V
V _{IN(0)}	Logical “0” Input Voltage	V _{CC} = 5.0V			1.5	V
		V _{CC} = 10V			2.0	V
V _{OUT(1)}	Logical “1” Output Voltage (RB Output Only)	V _{CC} = 5.0V, I _O = −10 μA	4.5			V
		V _{CC} = 10V, I _O = −10 μA	9.0			V
V _{OUT(0)}	Logical “0” Output Voltage	V _{CC} = 5.0V, I _O = 10 μA			0.5	V
		V _{CC} = 10V, I _O = 10 μA			1.0	V
I _{IN(1)}	Logical “1” Input Current	V _{CC} = 15.0V, V _{IN} = 15V		0.005	1.0	μA
I _{IN(0)}	Logical “0” Input Current	V _{CC} = 15.0V, V _{IN} = 0V	−1.0	−0.005		μA
I _{CC}	Supply Current	V _{CC} = 15V		0.05	300	μA
CMOS/LPTTL INTERFACE						
V _{IN(1)}	Logical “1” Input Voltage	54C, V _{CC} = 4.5V	V _{CC} − 1.5			V
		74C, V _{CC} = 4.75V	V _{CC} − 1.5			V
V _{IN(0)}	Logical “0” Input Voltage	54C, V _{CC} = 4.5V			0.8	V
		74C, V _{CC} = 4.75V			0.8	V
V _{OUT(1)}	Logical “1” Output Voltage (RB Output Only)	54C, V _{CC} = 4.5V, I _O = −50 μA	2.4			V
		74C, V _{CC} = 4.75V, I _O = −50 μA	2.4			V
V _{OUT(0)}	Logical “0” Output Voltage	54C, V _{CC} = 4.5V, I _O = 360 μA			0.4	V
		74C, V _{CC} = 4.75V, I _O = 360 μA			0.4	V
OUTPUT DRIVE (See 54C/74C Family Characteristics Data Sheet)						
I _{SOURCE}	Output Source Current (P-Channel)(RB Output Only)	V _{CC} = 4.75V, V _{OUT} = 0.4V			−0.80	mA
		V _{CC} = 10V, V _{OUT} = 0.5V			−4.0	mA
I _{SINK}	Output Sink Current (N-Channel)	V _{CC} = 5.0V, V _{OUT} = V _{CC} T _A = 25°C	1.75	3.6		mA
I _{SINK}	Output Sink Current (N-Channel)	V _{CC} = 10V, V _{OUT} = V _{CC} T _A = 25°C	8.0	16		mA
I _{SOURCE}	Output Source Current (NPN Bipolar)	V _{CC} = 5.0V, V _{OUT} = 3.4V	−20	−50		mA
		V _{CC} = 5.0V, V _{OUT} = 3.0V		−65		mA
		V _{CC} = 10V, V _{OUT} = 8.4V	−20	−50		mA
		V _{CC} = 10V, V _{OUT} = 8.0V		−65		mA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: Capacitance is guaranteed by periodic testing.

Note 3: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics Application Note, AN-90.

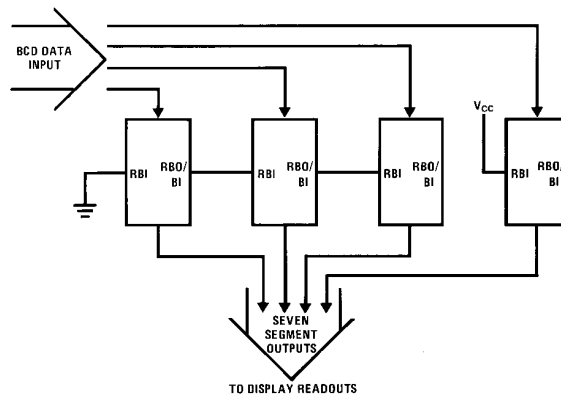
AC Electrical Characteristics* $T_A = 25^\circ\text{C}$, $C_L = 50\text{ pF}$, unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Units
t_{pd0}, t_{pd1}	Propagation Delay to a "1" or "0" on Segment Outputs from Data Inputs	$V_{CC} = 5.0\text{V}$		450	1500	ns
		$V_{CC} = 10\text{V}$		160	500	ns
t_{pd0}	Propagation Delay to a "0" on Segment Outputs from RB Input	$V_{CC} = 5.0\text{V}$		500	1600	ns
		$V_{CC} = 10\text{V}$		180	550	ns
t_{pd0}	Propagation Delay to a "0" on Segment Outputs from Blanking Input	$V_{CC} = 5.0\text{V}$		350	1200	ns
		$V_{CC} = 10\text{V}$		140	450	ns
t_{pd1}	Propagation Delay to a "1" on Segment Outputs from Lamp Test	$V_{CC} = 5.0\text{V}$		450	1500	ns
		$V_{CC} = 10\text{V}$		160	500	ns
t_{pd1}	Propagation Delay to a "1" on RB Output from RB Input	$V_{CC} = 5.0\text{V}$		600	2000	ns
		$V_{CC} = 10\text{V}$		250	800	ns
t_{pd0}	Propagation Delay to a "0" on RB Output from RB Input	$V_{CC} = 5.0\text{V}$		140	450	ns
		$V_{CC} = 10\text{V}$		50	150	ns

*AC Parameters are guaranteed by DC correlated testing.

Typical Applications

Typical Connection Utilizing the Ripple-Blanking Feature



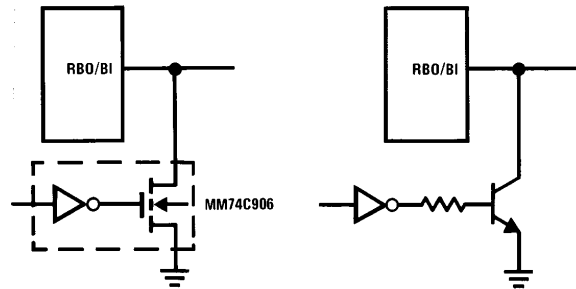
TO DISPLAY READOUTS

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First three stages will blank leading zeros, the fourth stage will not blank zeros.

Typical Applications (Continued)

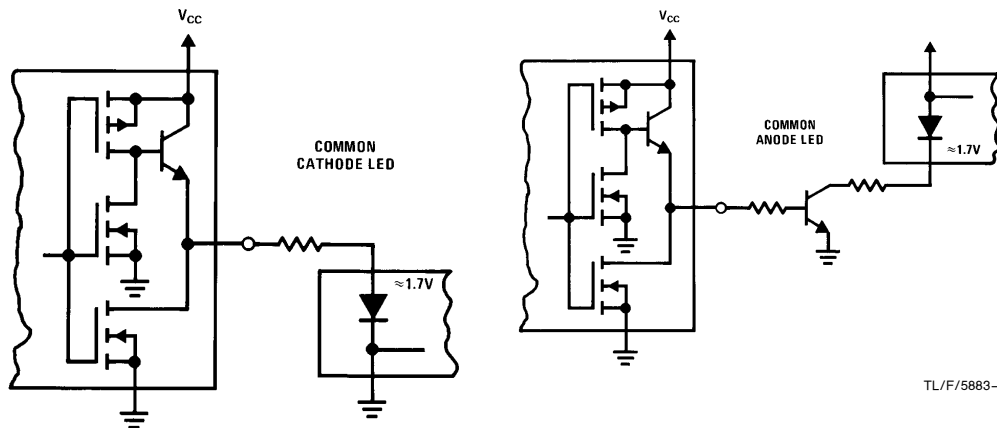
Blanking Input Connection Diagram



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When RBO/BI is forced low, all segment outputs are off regardless of the state of any other input condition.

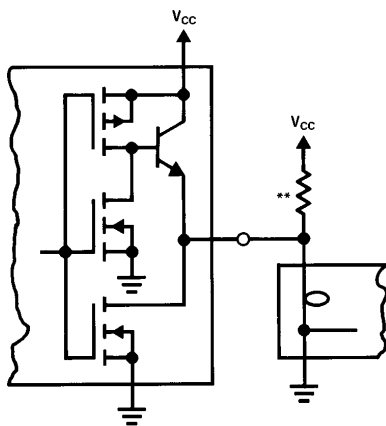
Light Emitting Diode (LED) Readout



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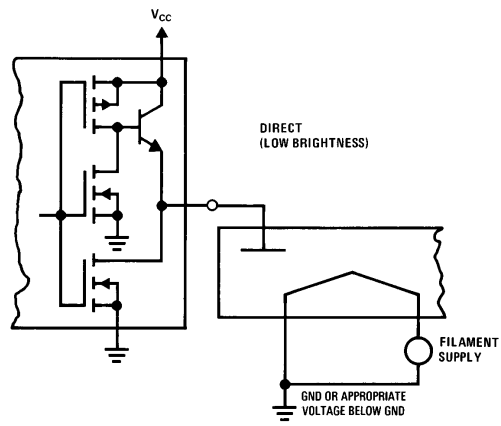
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Incandescent Readout



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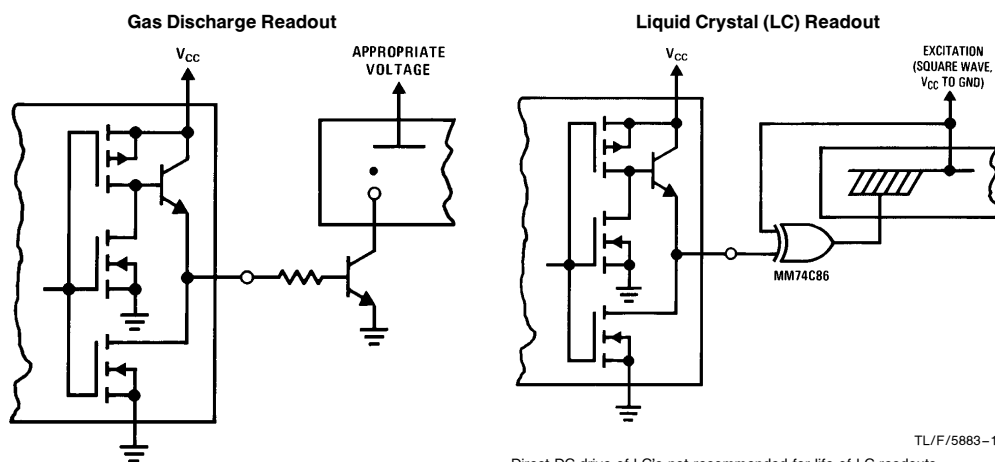
Fluorescent Readout



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**A filament pre-warm resistor is recommended to reduce filament thermal shock and increase the effective cold resistance of the filament.

Typical Applications (Continued)



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Direct DC drive of LC's not recommended for life of LC readouts.

Truth Table

Decimal or Function	Inputs						BI/RBO [†]	Outputs							Note
	LT	RBI	D	C	B	A		a	b	c	d	e	f	g	
0	H	H	L	L	L	L	H	H	H	H	H	H	H	L	1
1	H	X	L	L	L	H	H	L	H	H	L	L	L	L	
2	H	X	L	L	H	L	H	H	H	L	H	H	L	H	
3	H	X	L	L	H	H	H	H	H	H	H	L	L	H	
4	H	X	L	H	L	L	H	L	H	H	L	L	H	H	
5	H	X	L	H	L	H	H	H	L	H	H	L	H	H	
6	H	X	L	H	H	L	H	L	L	H	H	H	H	H	
7	H	X	L	H	H	H	H	H	H	H	L	L	L	L	
8	H	X	H	L	L	L	H	H	H	H	H	H	H	H	
9	H	X	H	L	L	H	H	H	H	H	L	L	H	H	
10	H	X	H	L	H	L	H	L	L	L	H	H	L	H	
11	H	X	H	L	H	H	H	L	L	H	H	L	L	H	
12	H	X	H	H	L	L	H	L	H	L	L	L	H	H	
13	H	X	H	H	L	H	H	H	L	L	H	L	H	H	
14	H	X	H	H	H	L	H	L	L	L	H	H	H	H	
15	H	X	H	H	H	H	H	L	L	L	L	L	L	L	
BI	X	X	X	X	X	X	L	L	L	L	L	L	L	L	2
RBI	H	L	L	L	L	L	L	L	L	L	L	L	L	L	
LT	L	X	X	X	X	X	H	H	H	H	H	H	H	H	

H = high level, L = low level, X = irrelevant

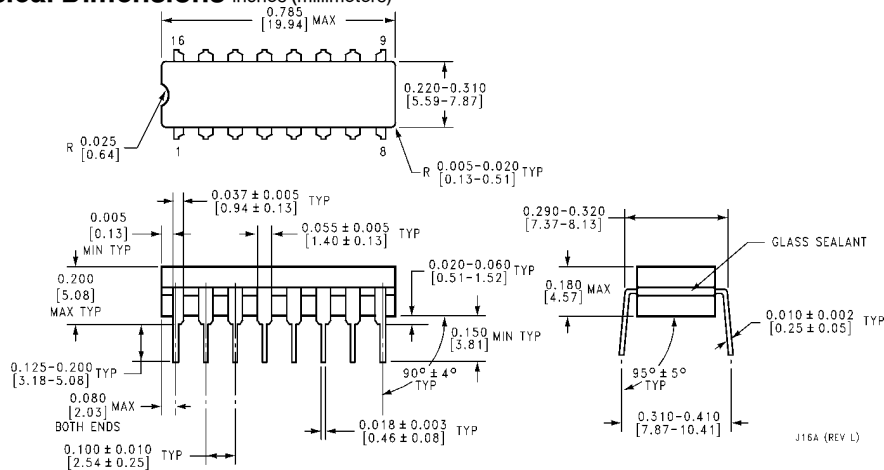
Note 1: The blanking input (BI) must be open when output functions 0–15 are desired. The ripple-blanking input (RBI) must be high, if blanking of a decimal zero is not desired.

Note 2: When a low logic level is applied directly to the blanking input (BI), all segment outputs are low regardless of the level of any other input.

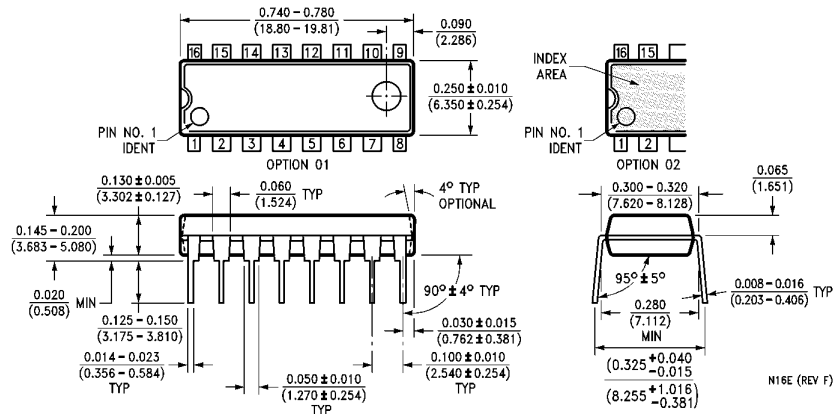
Note 3: When ripple-blanking input (RBI) and inputs A, B, C, and D are at a low level with the lamp-test input high, all segment outputs go low and the ripple-blanking output (RBO) goes to a low level (response condition).

Note 4: When the blanking input/ripple-blanking output (BI/RBO) is open and a low is applied to the lamp-test input, all segment outputs are high.

[†]One BI/RBO is wire-AND logic serving as blanking input (BI) and/or ripple-blanking output (RBO).

Physical Dimensions inches (millimeters)

Ceramic Dual-In-Line Package (J)
Order Number MM54C48J or MM74C48J
NS Package Number J16A



Molded Dual-In-Line Package (N)
Order Number MM54C48N or MM74C48N
NS Package Number N16E

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